



24th IEEE Non-Volatile Memory Technology Symposium (IEEE NVMTS 2026)

October 13-15, 2026

Takeda Hall (5 floor), The University of Tokyo, Japan

October 13 (Tue)

9:00		9:20	Opening Ceremony
9:00	~	9:20	Conference Chair Announcement & Opening Remarks
9:20		10:00	Keynote Talk Session, Chair: Daisaburo Takashima
9:20	~	10:00	Keynote Talk I: Mitsuhiro Noda, Kioxia, Japan
10:00	~	11:15	Session 01 - Flash Memory I, Chair: Daisaburo Takashima
10:00	~	10:25	Akira Goda, Micron, USA
10:25	~	10:50	Hang-Ting Lue, Macronix, Taiwan
10:50	~	11:15	Sanghun Jeon, KAIST, South Korea
11:15	~	11:40	Coffee Break
11:40	~	12:30	Session 02 - MRAM, Chair: Daniele Leonelli
11:40	~	12:05	Tomoya Saito, Renesas Electronics, Japan
12:05	~	12:30	Hongxi Liu, Truth Memory, China
12:30	~	14:00	Lunch
14:00	~	14:50	Session 03 - Chalcogenide Memory I, Chair: Chair: Eilam Yalon
14:00	~	14:25	Wei Zhang, LJM, UK
14:25	~	14:50	Atsuya Okazaki, IBM Research, Japan
14:55	~	15:45	Session 04 - NVDRAM, Chair: Scott Sills
14:55	~	15:20	Shoichi Kabuyanagi, Kioxia
15:20	~	15:45	Roberto Guido, NaMLab
15:50	~	16:40	Session 05 - RRAM, Chair: Daniele Garbin
15:50	~	16:15	Gabriel Molas, Weebit Nano, Israel
16:15	~	16:40	Kyung Seok Woo, UNIST, Korea
16:40	~	19:10	Coffee Break & Poster Session

October 14 (Wed)

8:30		9:10	Keynote Talk Session, Chair: Kasidit Toprasertpong
8:30	~	9:10	Keynote Talk II: Alessandro Calderoni, Micron, USA
9:10	~	10:25	Session 06 - FeRAM I, Chair: Kasidit Toprasertpong
9:10	~	9:35	Miyu Yoshida, Sony Semiconductor Solutions, Japan
9:35	~	10:00	Nicolo Ronchi, IMEC, Belgium
10:00	~	10:25	Xiao Gong, NUS, Singapore
10:25	~	10:50	Coffee Break
10:50	~	11:15	Session 07 - Photonic Memory, Chair: Aaron Thean
10:50	~	11:15	Mitsuru Takenaka, U of Tokyo, Japan
11:20	~	12:35	Session 08 - Chalcogenide Memory II, Chair: Ilya Karpov
11:20	~	11:45	Innocenzo Tortorelli, Micron, USA
11:45		12:10	Andrea Redaelli, STMicroelectronics, Italy
12:10	~	12:35	Ghazi Sarwat Syed, IBM Research, Switzerland
12:35	~	14:00	Lunch
14:00	~	15:15	Session 09 - FeRAM II, Kasidit Toprasertpong
14:00	~	14:25	Chun-Jung Su, National Yang Ming Chiao Tung University, Taiwan
14:25		14:50	Asif Khan, Georgia Institute of Technology, USA
14:50		15:15	Pavan Nukala, Indian Institute of Science, India
15:15	~	18:00	Coffee Break & Poster Session
18:30	~	20:30	Banquet

Oct. 15 (Thu)

8:30		9:45	Session 10 - Flash Memory II, Chair: Daisaburo Takashima
8:30	~	8:55	Fumie Kikushima, Kioxia, Japan
8:55	~	9:20	Xiang Yang, Sandisk, USA
9:20	~	9:45	Sijung Yoo, SAIT, Samsung Electronics, South Korea
9:50	~	11:05	Session 11 - FeRAM III, Chair: Laurent Grenouillet
9:50	~	10:15	Dina Triyoso, Tokyo Electron, America
10:15	~	10:40	Min Hyuk Park, Seoul National University, South Korea
10:40		11:05	Sourav De, National Tsing Hua University, Taiwan
11:05	~	11:30	Coffee Break
11:30	~	12:20	Session 12 - Neuromorphic Devices. Chair: Ilya Karpov
11:30	~	11:55	Laura Bégon-Lours, ETH Zurich, Switzerland
11:55	~	12:20	Sreetosh Goswami, Indian Institute of Science, India
12:20		12:45	Duygu Kuzum, U of California San Diego, USA
12:40	~	14:00	Lunch
14:00	~	14:50	Session 13 - In-Memory and Near-Memory Computing, Chair: Masaharu Kobayashi
14:00	~	14:25	Ken Takeuchi, U of Tokyo, Japan
14:25	~	14:50	Ming Liu, Chinese Academy Of Science, China
14:55	~	15:45	Session 14 - Memory System Technology, Chair: Shigeki Tomishima
14:55		15:20	Alessio Spessot, IMEC, Belgium
15:20		15:45	Kento Sato, RIKEN R-CCS, Japan
15:50		16:40	Session 15 - FeRAM IV, Chair: Laurent Grenouillet
15:50		16:15	Thomas Kampfe, TU Braunschweig, Germany
16:15		16:40	Georg Schönweger, Kiel University, Germany
16:45	~	17:15	Poster Awards and Closing Ceremony